

## **KSC2330**

### **Color TV Chroma Output**

- Collector-Base Voltage: V<sub>CBO</sub>=300V
  Current Gain Bandwidth Product: f<sub>T</sub>=50MHz (TYP.)



1. Emitter 2. Collector 3. Base

## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	300	V
V <sub>CEO</sub>	Collector-Emitter Voltage	300	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current	100	mA
P <sub>C</sub>	Collector Power Dissipation	1	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ +150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise notd

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	300			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =5mA, I <sub>B</sub> =0	300			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E=100\mu A, I_C=0$	7			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =200V, I <sub>E</sub> =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =10V, I <sub>C</sub> =20mA	40		240	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =30V, I <sub>C</sub> =10mA		50		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		4		pF

## **h**<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240

# **Typical Characteristics**

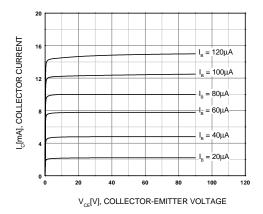


Figure 1. Static Characteristic

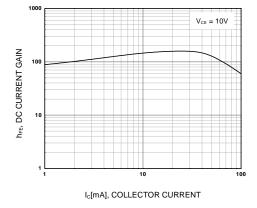


Figure 2. DC current Gain

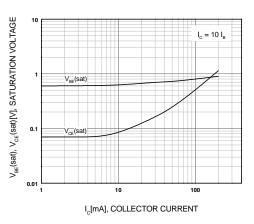


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

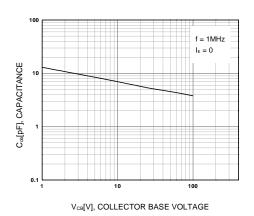


Figure 4. Collector Output Capacitance

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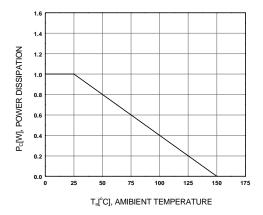
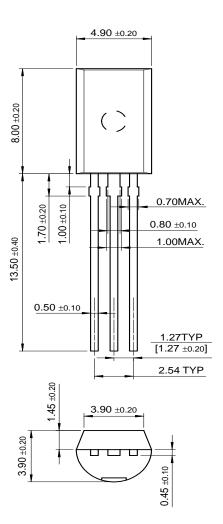


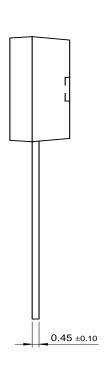
Figure 5. Power Derating



# **Package Dimensions**

## TO-92L





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E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franc	hise™	OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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